74HC245; 74HCT245

Octal bus tranceiver; 3-state Rev. 03 — 31 January 2005

**Product data sheet** 

#### 1. **General description**

The 74HC245; 74HCT245 is a high-speed Si-gate CMOS device and is pin compatible with Low-Power Schottky TTL (LSTTL).

The 74HC245; 74HCT245 is an octal transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The 74HC245; 74HCT245 features an output enable input (OE) for easy cascading and a send/receive input (DIR) for direction control. OE controls the outputs so that the buses are effectively isolated.

The 74HC245; 74HCT245 is similar to the 74HC640; 74HCT640 but has true (non-inverting) outputs.

#### 2. Features

- Octal bidirectional bus interface
- Non-inverting 3-state outputs
- Multiple package options
- Complies with JEDEC standard no. 7A
- ESD protection:
  - HBM EIA/JESD22-A114-B exceeds 2000 V
  - MM EIA/JESD22-A115-A exceeds 200 V
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C

#### **Quick reference data** 3.

Table 1: Quick reference data GND = 0 V;  $T_{amb} = 25 \circ C$ ;  $t_r = t_f = 6 ns$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Type 74H0	2245					
t <sub>PHL</sub> , t <sub>PLH</sub>	propagation delay An to Bn or Bn to An	C <sub>L</sub> = 15 pF; V <sub>CC</sub> = 5 V	-	7	-	ns
CI	input capacitance		-	3.5	-	pF
C <sub>I/O</sub>	input/output capacitance		-	10	-	pF
C <sub>PD</sub>	power dissipation capacitance per transceiver	$V_I = GND$ to $V_{CC}$	<u>[1]</u> -	30	-	pF
Туре 74НСТ245						
t <sub>PHL</sub> , t <sub>PLH</sub>	propagation delay An to Bn or Bn to An	C <sub>L</sub> = 15 pF; V <sub>CC</sub> = 5 V	-	10	-	ns



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Table 1:	Quick refe	rence data	continued
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$GND = 0 V_{i}$	; T <sub>amb</sub> = 25	° <i>C</i> ; $t_r = t_f = 6$ ns.
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
CI	input capacitance		-	3.5	-	pF
C <sub>I/O</sub>	input/output capacitance		-	10	-	pF
C <sub>PD</sub>	power dissipation capacitance per transceiver	$V_I = GND$ to $V_{CC} - 1.5$ V	<u>[1]</u> -	30	-	pF

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma \ (C_L \times V_{CC}{}^2 \times f_o)$  = sum of outputs.

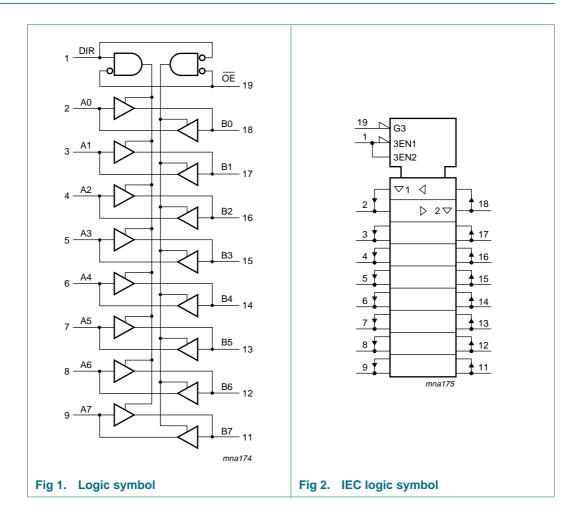
# 4. Ordering information

### Table 2:Ordering information

Type number	Package					
	Temperature range	Name	Description	Version		
74HC245N	–40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1		
74HC245D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1		
74HC245PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1		
74HC245DB	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1		
74HC245BQ	–40 °C to +125 °C	DHVQFN20	plastic dual-in-line compatible thermal enhanced very thin quad flat package no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm	SOT764-1		
74HCT245N	–40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1		
74HCT245D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1		
74HCT245PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1		
74HCT245DB	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1		
74HCT245BQ	–40 °C to +125 °C	DHVQFN20	plastic dual-in-line compatible thermal enhanced very thin quad flat package no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm	SOT764-1		



# 5. Functional diagram

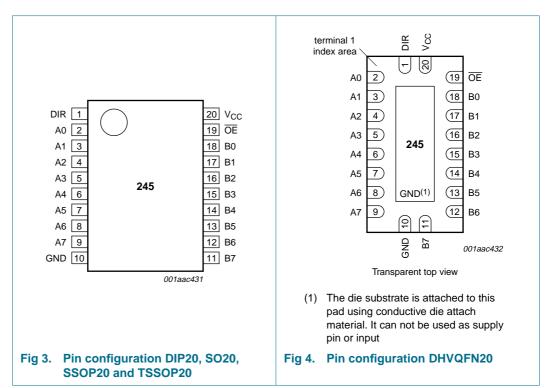




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# 6. Pinning information

## 6.1 Pinning



## 6.2 Pin description

### Table 3:Pin description

Symbol	Pin	Description
DIR	1	direction control
A0	2	data input/output
A1	3	data input/output
A2	4	data input/output
A3	5	data input/output
A4	6	data input/output
A5	7	data input/output
A6	8	data input/output
A7	9	data input/output
GND	10	ground (0 V)
B7	11	data input/output
B6	12	data input/output
B5	13	data input/output
B4	14	data input/output
B3	15	data input/output
B2	16	data input/output

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Table 3:	Pin description .	continued
Symbol	Pin	Description
B1	17	data input/output
B0	18	data input/output
ŌĒ	19	output enable input (active LOW)
V <sub>CC</sub>	20	supply voltage

# 7. Functional description

## 7.1 Function table

Table 4:	Function table [1]					
•			Input/outpu	Input/output		
OE		DIR	An	Bn		
L		L	A = B	input		
L		Н	input	B = A		
Н		Х	Z	Z		

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high-impedance OFF-state.

## 8. Limiting values

### Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input diode current	$V_{\rm I}$ < –0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I <sub>OK</sub>	output diode current	$V_{O} < -0.5 V \text{ or}$ $V_{O} > V_{CC} + 0.5 V$	-	±20	mA
I <sub>O</sub>	output source or sink current	$V_{\rm O}$ = –0.5 V to $V_{\rm CC}$ + 0.5 V	-	±35	mA
I <sub>CC</sub> , I <sub>GND</sub>	V <sub>CC</sub> or GND current		-	±70	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation		<u>[1]</u>		
	DIP20 package		-	750	mW
	SO20, SSOP20, TSSOP20 and DHVQFN20 packages		-	500	mW

For DIP20 packages: above 70 °C, P<sub>tot</sub> derates linearly with 12 mW/K.
 For SO20 packages: above 70 °C, P<sub>tot</sub> derates linearly with 8 mW/K.
 For SSOP20 and TSSOP20 packages: above 60 °C, P<sub>tot</sub> derates linearly with 5.5 mW/K.
 For DHVQFN20 packages: above 60 °C, P<sub>tot</sub> derates linearly with 4.5 mW/K.

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# 9. Recommended operating conditions

Table 6:	Recommended ope	erating conditions				
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Type 74H	IC245					
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
t <sub>r</sub> , t <sub>f</sub>	input rise and fall times	$V_{CC} = 2.0 V$	-	-	1000	ns
		$V_{CC} = 4.5 V$	-	6.0	500	ns
		$V_{CC} = 6.0 V$	-	-	400	ns
T <sub>amb</sub>	ambient temperatur	e	-40	-	+125	°C
Type 74H	ICT245					
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
t <sub>r</sub> , t <sub>f</sub>	input rise and fall times	$V_{CC}$ = 4.5 V	-	6.0	500	ns
T <sub>amb</sub>	ambient temperatur	e	-40	-	+125	°C

# **10. Static characteristics**

### Table 7: Static characteristics type 74HC245

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T <sub>amb</sub> = 25	°C					
VIH	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	1.2	-	V
		$V_{CC} = 4.5 V$	3.15	2.4	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 2.0 V$	-	0.8	0.5	V
		$V_{CC} = 4.5 V$	-	2.1	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	5.9	6.0	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V

Table 7:	Static characteristics type 74HC24	5 continued
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At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Un
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	-	0	0.1	V
		$I_{O} = 20 \ \mu\text{A}; \ V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	-	0	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
I <sub>LI</sub>	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±0.1	μA
I <sub>oz</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } GND;$ $V_{CC} = 6.0 \text{ V}$	-	-	±0.5	μA
lcc	quiescent supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 6.0 \ V \end{array}$	-	-	8.0	μA
CI	input capacitance		-	3.5	-	pF
C <sub>I/O</sub>	input/output capacitance		-	10	-	pF
T <sub>amb</sub> = -40	) °C to +85 °C					
VIH	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	-	-	V
	-	$V_{CC} = 4.5 V$	3.15	-	-	V
		$V_{CC} = 6.0 V$	4.2	-	-	V
VIL	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
	-	V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		$V_{CC} = 6.0 V$	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	5.9	-	-	V
		$I_0 = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_0 = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
02		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	-	-	0.1	V
		$I_{\rm O} = 6.0 \text{ mA}; V_{\rm CC} = 4.5 \text{ V}$	-	-	0.33	V
		$I_0 = 7.8 \text{ mA; } V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
ILI	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } GND;$ $V_{CC} = 6.0 \text{ V}$	-	-	±5.0	μA
lcc	quiescent supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA
Γ <sub>amb</sub> = -40	) °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		$V_{\rm CC} = 6.0 \text{ V}$	4.2	_	-	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 2.0 V$	-	-	0.5	V
		$V_{CC} = 4.5 V$	-	-	1.35	V
		$V_{CC} = 6.0 V$	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$		-		
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$		-		
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
ILI	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } GND;$ $V_{CC} = 6.0 \text{ V}$	-	-	±10.0	μA
I <sub>CC</sub>	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μA

## Table 7: Static characteristics type 74HC245 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

### Table 8: Static characteristics type 74HCT245

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	°C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	1.6	-	V
VIL	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I <sub>O</sub> = -20 μA	4.4	4.5	-	V
		$I_{O} = -6 \text{ mA}$	3.98	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$				
		I <sub>O</sub> = 20 μA	-	0	0.1	V
		I <sub>O</sub> = 6.0 mA	-	0.15	0.26	V
ILI	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	μA
l <sub>oz</sub>	OFF-state output current	$      V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 5.5 \text{ V};                                   $	-	-	±0.5	μA
I <sub>CC</sub>	quiescent supply current	$V_I = V_{CC} \text{ or GND}; I_O = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$	-	-	8.0	μA

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Symbol	Parameter	Conditions		Тур	Max	Uni
∆I <sub>CC</sub>	additional quiescent supply current per input pin	$V_I = V_{CC} - 2.1$ V; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A				
	An or Bn inputs		-	40	144	μΑ
	OE input		-	150	540	μΑ
	DIR input		-	90	324	μΑ
CI	input capacitance		-	3.5	-	pF
C <sub>I/O</sub>	input/output capacitance	e		10	-	pF
$\Gamma_{amb} = -40$	0 °C to +85 °C					
VIH	HIGH-level input voltage	$V_{CC} = 4.5 V \text{ to } 5.5 V$	2.0	-	-	V
VIL	LOW-level input voltage	$V_{CC} = 4.5 V \text{ to } 5.5 V$	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I <sub>O</sub> = -20 μA	4.4	-	-	V
		I <sub>O</sub> = -6 mA	3.84	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$				
		I <sub>O</sub> = 20 μA	-	-	0.1	V
		$I_0 = 6.0 \text{ mA}$	-	-	0.33	V
LI	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 5.5$ V		-	±1.0	μA
loz	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 5.5 \text{ V};$ $V_O = V_{CC} \text{ or GND per input pin};$ other inputs at $V_{CC} \text{ or GND}; I_O = 0 \text{ A}$	-	-	±5.0	μA
СС	quiescent supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μΑ
VI <sub>CC</sub>	additional quiescent supply current per input pin	$V_{I} = V_{CC} - 2.1 \text{ V}; \text{ other inputs at} \\ V_{I} = V_{CC} \text{ or GND}; \\ V_{CC} = 4.5 \text{ V to 5.5 V}; I_{O} = 0 \text{ A}$				
	An or Bn inputs		-	-	180	μΑ
	OE input		-	-	675	μA
	DIR input		-	-	405	μA
Γ <sub>amb</sub> = -4	0 °C to +125 °C					
VIH	HIGH-level input voltage	$V_{CC} = 4.5 V \text{ to } 5.5 V$	2.0	-	-	V
VIL	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
√он	HIGH-level output voltage	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$				
		I <sub>O</sub> = -20 μA	4.4	-	-	V
		$I_{O} = -6 \text{ mA}$	3.7	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		$I_{O} = 20 \mu\text{A}$	-	-	0.1	V
		$I_0 = 6.0 \text{ mA}$	-	-	0.4	V
LI	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	±1.0	μA
loz	OFF-state output current	$V_{I} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$ $V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 5.5 \text{ V};$ $V_{O} = V_{CC} \text{ or GND per input pin;}$ other inputs at $V_{CC} \text{ or GND}; I_{O} = 0 \text{ A}$		-	±10	μΑ

#### Static characteristics type 74HCT245 ... continued Table 8:

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CC</sub>	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μA
$\Delta I_{CC}$	additional quiescent supply current per input pin	$V_I = V_{CC} - 2.1 \text{ V}$ ; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_O = 0 \text{ A}$				
	An or Bn inputs		-	-	196	μA
	OE input		-	-	735	μA
	DIR input		-	-	441	μA

### Static characteristics type 74HCT245 ... continued Table 8:

ound 010

# **11. Dynamic characteristics**

#### Dynamic characteristics type 74HC245 Table 9:

GND = 0 V; test circuit see Figure 7.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	°C					
t <sub>PHL</sub> , t <sub>PLH</sub>	propagation delay An to Bn or Bn	see Figure 5				
	to An	$V_{CC} = 2.0 V$	-	25	90	ns
		$V_{CC} = 4.5 V$	-	9	18	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	7	-	ns
		$V_{CC} = 6.0 V$	-	7	15	ns
t <sub>PZH</sub> , t <sub>PZL</sub>	3-state output enable time $\overline{OE}$ to	see Figure 6				
	An or $\overline{OE}$ to Bn	$V_{CC} = 2.0 V$	-	30	150	ns
		$V_{CC} = 4.5 V$	-	11	30	ns
		$V_{CC} = 6.0 V$	-	9	26	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	3-state output disable time $\overline{OE}$ to	see Figure 6				
	An or OE to Bn	$V_{CC} = 2.0 V$	-	41	150	ns
		$V_{CC} = 4.5 V$	-	15	30	ns
		$V_{CC} = 6.0 V$	-	12	26	ns
t <sub>THL</sub> , t <sub>TLH</sub>	output transition time	see Figure 5				
		$V_{CC} = 2.0 V$	-	14	60	ns
		$V_{CC} = 4.5 V$	-	5	12	ns
		$V_{CC} = 6.0 V$	-	4	10	ns
C <sub>PD</sub>	power dissipation capacitance per transceiver	$V_I = GND$ to $V_{CC}$	<u>[1]</u> -	30	-	pF
T <sub>amb</sub> = -40	°C to +85 °C					
t <sub>PHL</sub> , t <sub>PLH</sub>	propagation delay An to Bn or Bn	see Figure 5				
	to An	$V_{CC} = 2.0 V$	-	-	115	ns
		$V_{CC} = 4.5 V$	-	-	23	ns
		V <sub>CC</sub> = 6.0 V	-	-	20	ns

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**Product data sheet** 

# 74HC245; 74HCT245

Octal bus tranceiver; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>PZH</sub> , t <sub>PZL</sub>	3-state output enable time OE to	see Figure 6				
	An or $\overline{OE}$ to Bn	$V_{CC} = 2.0 V$	-	-	190	ns
		$V_{CC} = 4.5 V$	-	-	38	ns
		$V_{CC} = 6.0 V$	-	-	33	ns
<sub>PHZ</sub> , t <sub>PLZ</sub>	3-state output disable time $\overline{OE}$ to	see Figure 6				
	An or $\overline{OE}$ to Bn	$V_{CC} = 2.0 V$	-	-	190	ns
		$V_{CC} = 4.5 V$	-	-	38	ns
		$V_{CC} = 6.0 V$	-	-	33	ns
t <sub>THL</sub> , t <sub>TLH</sub>	output transition time	see Figure 5				
		$V_{CC} = 2.0 V$	-	-	75	ns
		$V_{CC} = 4.5 V$	-	-	15	ns
		V <sub>CC</sub> = 6.0 V	-	-	13	ns
T <sub>amb</sub> = -40	°C to +125 °C					
t <sub>PHL</sub> , t <sub>PLH</sub>	propagation delay An to Bn or Bn to An	see Figure 5				
		$V_{CC} = 2.0 V$	-	-	135	ns
		$V_{CC} = 4.5 V$	-	-	27	ns
		$V_{CC} = 6.0 V$	-	-	23	ns
t <sub>PZH</sub> , t <sub>PZL</sub>	3-state output enable time $\overline{OE}$ to	see Figure 6				
	An or $\overline{OE}$ to Bn	$V_{CC} = 2.0 V$	-	-	225	ns
		$V_{CC} = 4.5 V$	-	-	45	ns
		$V_{CC} = 6.0 V$	-	-	38	ns
PHZ, t <sub>PLZ</sub>	3-state output disable time $\overline{OE}$ to	see Figure 6				
	An or $\overline{OE}$ to Bn	$V_{CC} = 2.0 V$	-	-	225	ns
		$V_{CC} = 4.5 V$	-	-	45	ns
		$V_{CC} = 6.0 V$	-	-	38	ns
t <sub>THL</sub> , t <sub>TLH</sub>	output transition time	see Figure 5				
		V <sub>CC</sub> = 2.0 V	-	-	90	ns
		$V_{CC} = 4.5 V$	-	-	18	ns
		V <sub>CC</sub> = 6.0 V	-	-	15	ns

# Table 9: Dynamic characteristics type 74HC245 ...continued

 $f_i = input frequency in MHz;$ 

 $f_o = output frequency in MHz;$ 

 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma \ (C_L \times V_{CC}{}^2 \times f_o)$  = sum of outputs.

### Table 10: Dynamic characteristics type 74HCT245

GND = 0 V; test circuit see <u>Figure 7</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25 °	°C					
t <sub>PHL</sub> , t <sub>PLH</sub>	propagation delay An to Bn or Bn	see Figure 5				
	to An	$V_{CC} = 4.5 V$	-	12	22	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	10	-	ns
t <sub>PZH</sub> , t <sub>PZL</sub>	3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	$V_{CC}$ = 4.5 V; see Figure 6	-	16	30	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	$V_{CC}$ = 4.5 V; see Figure 6	-	16	30	ns
t <sub>THL</sub> , t <sub>TLH</sub>	output transition time	V <sub>CC</sub> = 4.5 V; see Figure 5	-	5	12	ns
C <sub>PD</sub>	power dissipation capacitance per transceiver	$V_{I}$ = GND to $V_{CC}$ – 1.5 V	<u>[1]</u> -	30	-	pF
T <sub>amb</sub> = -40	°C to +85 °C					
t <sub>PHL</sub> , t <sub>PLH</sub>	propagation delay An to Bn or Bn to An	$V_{CC}$ = 4.5 V; see <u>Figure 5</u>	-	-	28	ns
t <sub>PZH</sub> , t <sub>PZL</sub>	3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	$V_{CC}$ = 4.5 V; see Figure 6	-	-	38	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	$V_{CC}$ = 4.5 V; see Figure 6	-	-	38	ns
t <sub>THL</sub> , t <sub>TLH</sub>	output transition time	V <sub>CC</sub> = 4.5 V; see <u>Figure 5</u>	-	-	15	ns
T <sub>amb</sub> = -40	°C to +125 °C					
t <sub>PHL</sub> , t <sub>PLH</sub>	propagation delay An to Bn or Bn to An	$V_{CC}$ = 4.5 V; see <u>Figure 5</u>	-	-	33	ns
t <sub>PZH</sub> , t <sub>PZL</sub>	3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	$V_{CC}$ = 4.5 V; see Figure 6	-	-	45	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	$V_{CC}$ = 4.5 V; see Figure 6	-	-	45	ns
t <sub>THL</sub> , t <sub>TLH</sub>	output transition time	$V_{CC} = 4.5 V$ ; see Figure 5	-	-	18	ns

[1]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$ 

 $f_i = input frequency in MHz;$ 

 $f_0$  = output frequency in MHz;

 $C_L$  = output load capacitance in pF;

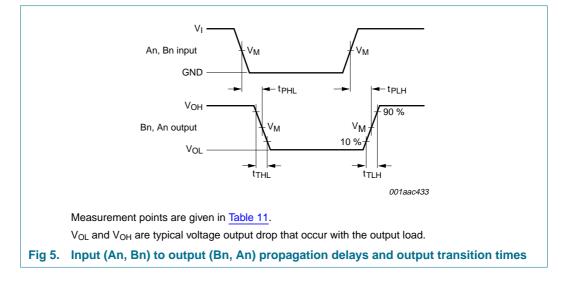
 $V_{CC}$  = supply voltage in V;

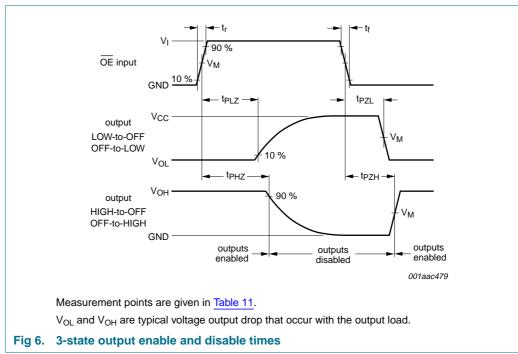
N = number of inputs switching;

 $\Sigma (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 



## 12. Waveforms



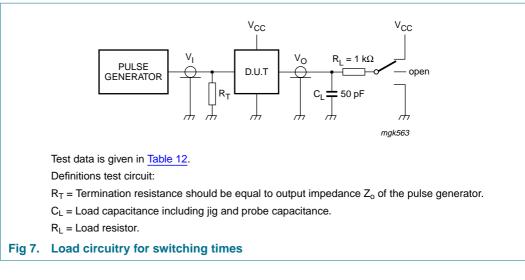


### Table 11: Measurement points

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC245	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74HCT245	1.3 V	1.3 V

# 74HC245; 74HCT245

## Octal bus tranceiver; 3-state



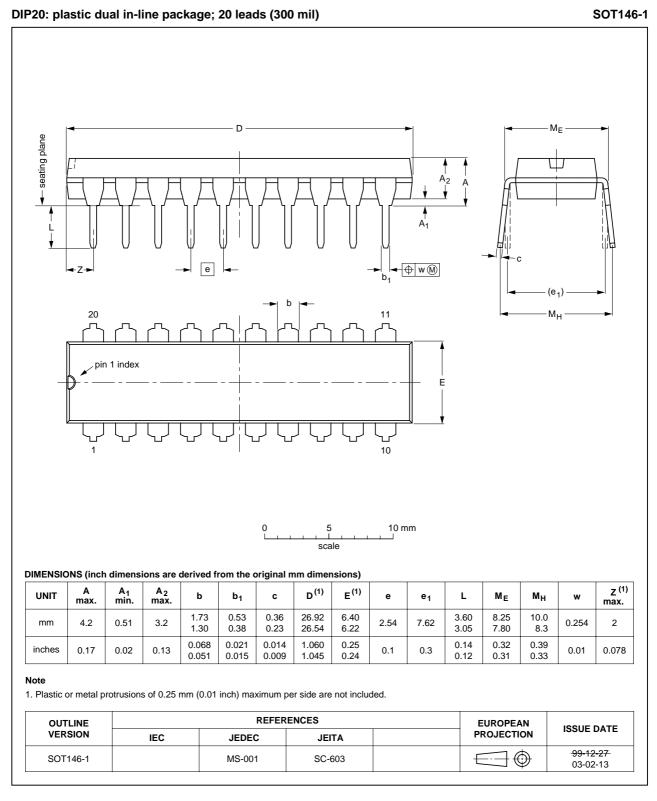
## Table 12: Test data

Туре	Input Test				
	VI	t <sub>r</sub> , t <sub>f</sub>	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
74HC245	V <sub>CC</sub>	6 ns	open	GND	V <sub>CC</sub>
74HCT245	3 V	6 ns	open	GND	V <sub>CC</sub>

74HC245; 74HCT245

Octal bus tranceiver; 3-state

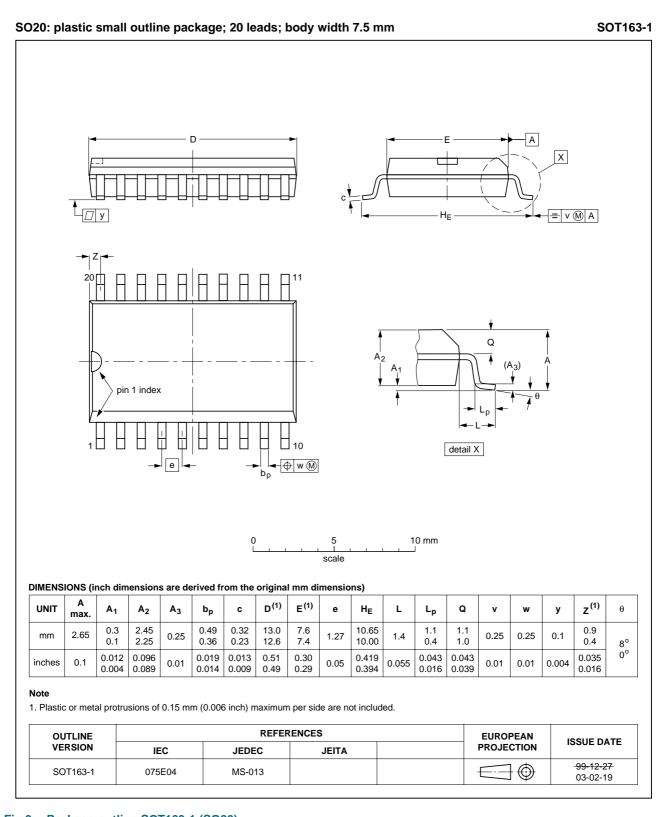
# 13. Package outline



## Fig 8. Package outline SOT146-1 (DIP20)

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## Fig 9. Package outline SOT163-1 (SO20)

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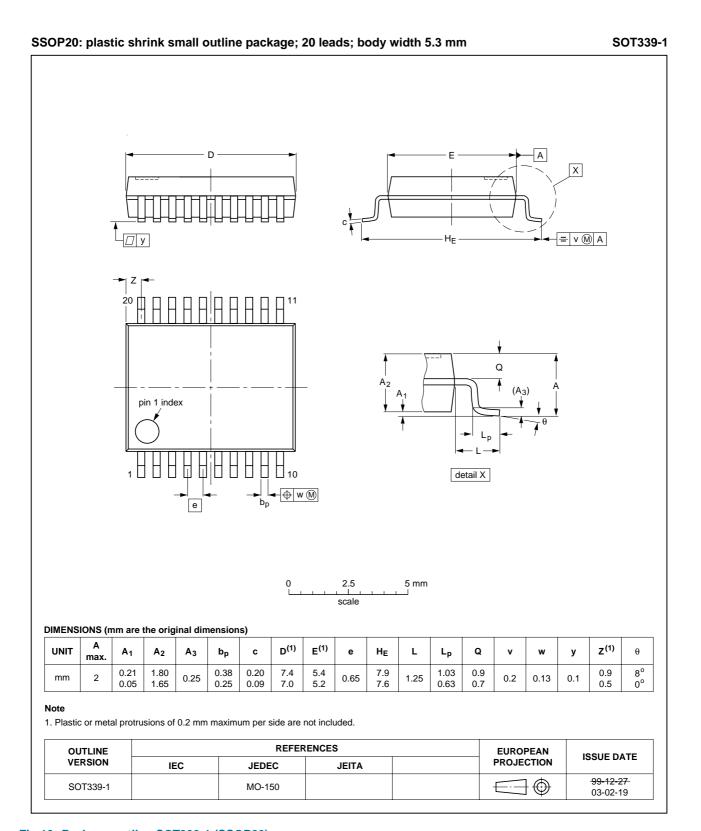


Fig 10. Package outline SOT339-1 (SSOP20)

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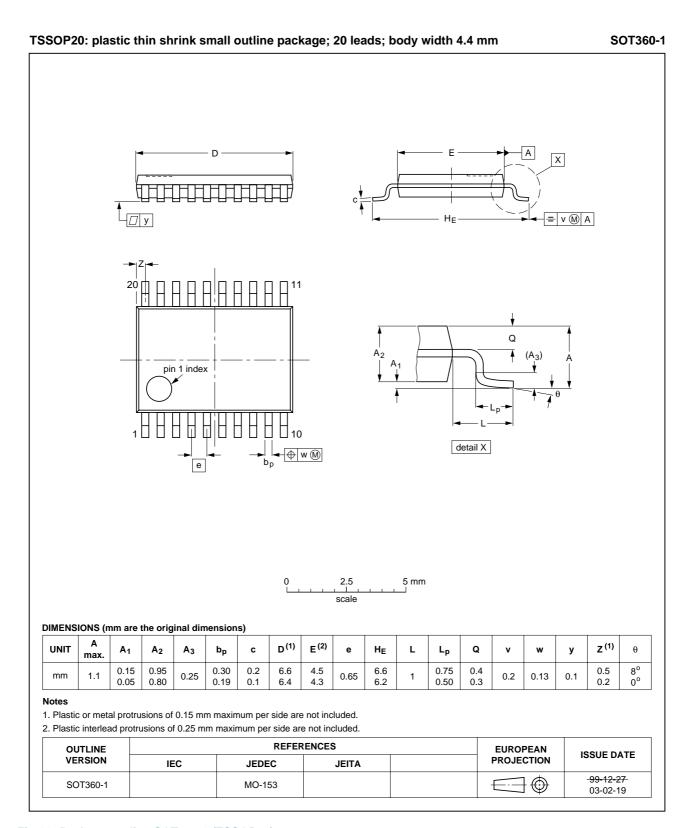
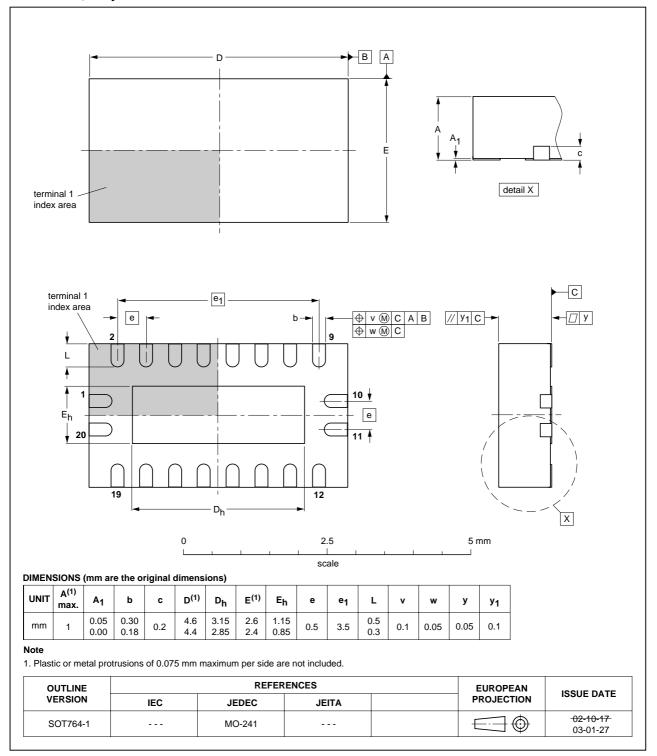


Fig 11. Package outline SOT360-1 (TSSOP20)

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DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

### Fig 12. Package outline SOT764-1 (DHVQFN20)

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# 14. Revision history

ory				
Release date	Data sheet status	Change notice	Doc. number	Supersedes
20050131	Product data sheet	-	9397 750 14502	74HC_HCT245_CNV_2
		•		v presentation and
				and <u>Section 13 "Package</u>
19930930	Product specification	-	-	-
	Release date 20050131 • The form informati • <u>Section 4</u> outline" a	Release date       Data sheet status         20050131       Product data sheet         • The format of this data sheet is information standard of Philips 3         • Section 4 "Ordering information outline" are modified to include	Release date         Data sheet status notice         Change notice           20050131         Product data sheet         -           • The format of this data sheet is redesigned to information standard of Philips Semiconductor         -           • Section 4 "Ordering information", Section 6 "For outline" are modified to include the DHVQFN:	Release date       Data sheet status notice       Change notice       Doc. number         20050131       Product data sheet       -       9397 750 14502         • The format of this data sheet is redesigned to comply with the new information standard of Philips Semiconductors       •       9397 750 14502         • Section 4 "Ordering information", Section 6 "Pinning information" a outline" are modified to include the DHVQFN20 package.       •

## 15. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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# 74HC245; 74HCT245

Octal bus tranceiver; 3-state

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